

Cite this: *Chem. Sci.*, 2021, 12, 1278

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Supertetrahedral polyanionic network in the first lithium phosphidoindate Li_3InP_2 – structural similarity to Li_2SiP_2 and Li_2GeP_2 and dissimilarity to Li_3AlP_2 and Li_3GaP_2 †

Tassilo M. F. Restle,^a Volker L. Deringer,^b Jan Meyer,^a Gabriele Raudaschl-Sieber^a and Thomas F. Fässler^{ib}*^a

Phosphide-based materials have been investigated as promising candidates for solid electrolytes, among which the recently reported Li_9AlP_4 displays an ionic conductivity of 3 mS cm^{-1} . While the phases Li–Al–P and Li–Ga–P have already been investigated, no ternary indium-based phosphide has been reported up to now. Here, we describe the synthesis and characterization of the first lithium phosphidoindate Li_3InP_2 , which is easily accessible *via* ball milling of the elements and subsequent annealing. Li_3InP_2 crystallizes in the tetragonal space group $I4_1/acd$ with lattice parameters of $a = 12.0007(2)$ and $c = 23.917(5)$ Å, featuring a supertetrahedral polyanionic framework of interconnected InP_4 tetrahedra. All lithium atoms occupy tetrahedral voids with no partial occupation. Remarkably, Li_3InP_2 is not isotypic to the previously reported homologues Li_3AlP_2 and Li_3GaP_2 , which both crystallize in the space group $Cmce$ and feature 2D layers of connected tetrahedra but no supertetrahedral framework. DFT computations support the observed stability of Li_3InP_2 . A detailed geometrical analysis leads to a more general insight into the structural factors governing lithium ion mobility in phosphide-based materials: in the non-ionic conducting Li_3InP_2 the Li ions exclusively occupy tetrahedral voids in the distorted close packing of P atoms, whereas partially filled octahedral voids are present in the moderate ionic conductors Li_2SiP_2 and Li_2GeP_2 .

Received 23rd October 2020
Accepted 26th November 2020

DOI: 10.1039/d0sc05851c

rsc.li/chemical-science

Introduction

All-solid-state batteries (ASSB) have recently become the focus of research as an attractive alternative to state-of-the-art liquid-based batteries due to their enhanced safety combined with high energy/power density and mechanical stability.^{1–7} One of the main obstacles for the commercialization of ASSBs is the difficulty to develop superionic solid conductors, which are crucial for fast ionic diffusion in ASSBs. Recently, our group investigated new classes of lithium ion conductors based on phosphides. Starting with Li_9SiP_4 in 2016, we introduced phosphidosilicates with an ionic conductivity of $4.5 \times 10^{-5} \text{ S cm}^{-1}$.⁸ Lately, in the Li-rich compound $\text{Li}_{14}\text{SiP}_6$ the conductivity was even higher with up to $1 \times 10^{-3} \text{ S cm}^{-1}$.⁹

Furthermore, we extended the system to the heavier tetravalent (group-14) homologues, phosphidogermanates, with two Li-ion conducting modifications of Li_8GeP_4 that show ionic conductivities of up to $8.6 \times 10^{-5} \text{ S cm}^{-1}$ and with $\text{Li}_{14}\text{GeP}_6$, which achieves an ionic conductivity of $1.7 \times 10^{-3} \text{ S cm}^{-1}$.^{10,11} The structural building units in these phosphides are $[\text{TtP}_4]^{8-}$ tetrahedra surrounded by lithium atoms (Tt = Si, Ge). They exhibit a huge structural variety, and by decreasing the amount of lithium, condensed and covalently connected tetrahedra are formed, thereby offering different polyanionic networks: $\text{Li}_{10}\text{Si}_2\text{P}_6$ features pairs of edge-sharing SiP_4 tetrahedra,¹² in $\text{Li}_2\text{SiP}_2/\text{Li}_2\text{GeP}_2$ and LiSi_2P_3 , respectively, SiP_4 and GeP_4 tetrahedra are condensed to networks of supertetrahedra.^{8,13,14} Layered structures have been reported as well: in $\text{Li}_3\text{Si}_3\text{P}_7$, vertex-sharing SiP_4 tetrahedra form double layers,¹² and LiGe_3P_3 is built up by a two dimensionally extended polyanion comprising GeP_4 and $\text{Ge}(\text{P}_3\text{Ge})$ tetrahedra.¹³

Phosphide-based materials as lithium ionic conductors originated from the aliovalent substitution of $[\text{TtS}_4]^{4-}$ tetrahedra, which are the main building block in sulfide-based conductors. This leads to analogous structures with more negatively charged $[\text{TtP}_4]^{8-}$ tetrahedra, which can therefore accommodate more lithium than the well-known sulfur-based

^aDepartment of Chemistry, Technische Universität München, Lichtenbergstraße 4, D-85747 Garching, Germany. E-mail: Thomas.Faessler@lrz.tum.de

^bDepartment of Chemistry, University of Oxford, South Parks Road, Oxford OX1 3QR, UK

† Electronic supplementary information (ESI) available: Experimental details, details of the crystal structure determination, experimental powder X-ray diffraction pattern, coordination polyhedra, differential scanning calorimetry thermogram, Nyquist plot. CSD 2026514. For ESI and crystallographic data in CIF or other electronic format see DOI: 10.1039/d0sc05851c



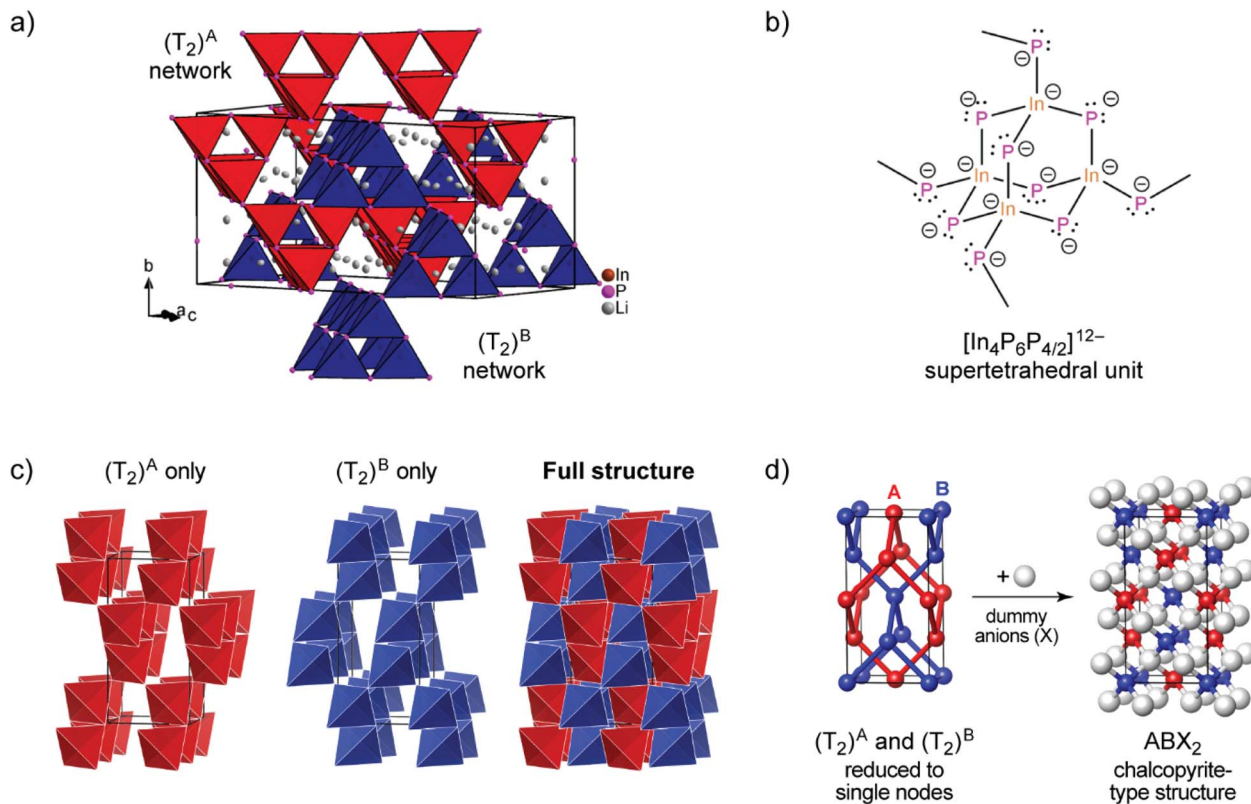


Fig. 1 (a) The crystal structure of Li_3InP_2 . The T_2 -supertetrahedra consist of four InP_4 tetrahedra and form two independent adamantane-like networks (the two networks, denoted as $(\text{T}_2)^{\text{A}}$ and $(\text{T}_2)^{\text{B}}$, are shown in red and blue color, respectively). Li^+ ions are located in tetrahedral voids of the distorted ccp of P atoms. Li, In and P atoms are depicted in grey, brown and purple color, respectively (displacement ellipsoids set at 90% at 150 K). Crystal data and structure refinement are shown in Tables S1–S4 in the ESI.† CSD 2026514 contains the ESI crystallographic data for this paper.† (b) Lewis structure with formal charges of the atoms. (c) The two independent adamantane-like supertetrahedral networks $(\text{T}_2)^{\text{A}}$ and $(\text{T}_2)^{\text{B}}$ and the penetration of the two networks (each T_2 unit is represented by a tetrahedron). (d) A simplified view of the structure, in which the center of gravity of each T_2 unit is represented by a colored sphere (“node”), inspired by ref. 18 Notice: the ABX_2 chalcopyrite structure type is formed by the formal insertion of X atoms shown as grey spheres. Structural drawings in panels (c) and (d) were created using VESTA.¹⁹

chemical environment. The chemical shift of the Li atoms is in the same range as those for related compounds like Li_9AlP_4 (4.2 ppm), Li_3AlP_2 (4.0 and 3.0 ppm), Li_3GaP_2 (4.1 and 3.4 ppm), Li_2SiP_2 (2.1 ppm from ^7Li MAS-NMR spectroscopy), and Li_2GeP_2 (3.6 and 2.4 ppm).^{8,13,15,16} Compared to the above-mentioned compounds with two signals in the ^6Li NMR spectrum, the

difference in local coordination, which is expressed by the P–Li–P angles, is the lowest for Li_3InP_2 (Li_3InP_2 : $104.99(8)$ – $113.25(8)^\circ$, Li_3AlP_2 : $100.0(3)$ – $116.647(1)^\circ$, Li_3GaP_2 : $102.258(1)$ – $115.2(3)^\circ$, Li_2GeP_2 : $84.68(1)$ – $158.89(2)^\circ$). The ^{31}P NMR spectrum displays a very broad, asymmetric signal in the range of -260 to -360 ppm. This range is typical for chemical shifts of two-fold

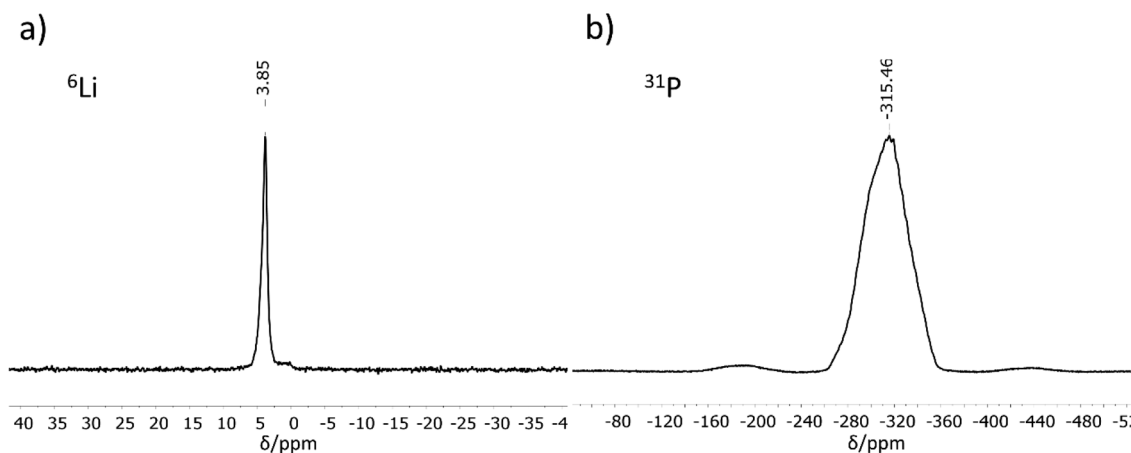


Fig. 2 ^6Li (a) and ^{31}P (b) MAS-NMR measurements performed for Li_3InP_2 .

connected P^{1-} atoms such as in Li_3AlP_2 (−300 and −308.7 ppm) or Li_3GaP_2 (−234.8 and −280.5 ppm).¹⁶ However, the signals of two-fold connected P^{1-} atoms in the related phosphidotetrelates are much more downfield shifted (Li_2SiP_2 : −129.1 and −241.5 ppm and Li_2GeP_2 : −59.9, −164.8 and −178.4 ppm) due to the deshielding of the more electronegative tetrel elements compared to indium.^{8,13}

Interestingly, only one ^{31}P NMR signal is observed for Li_3InP_2 , whereas two signals are obtained for all other related compounds. This correlates with the fact that the smallest distortion of the E–P–E bond angles is observed for Li_3InP_2 [106.411(9)–111.41(1)°] if compared to the others with E = Al, Ga, In, Si, Ge such as Li_3AlP_2 [78.298(1)–111.709(1)°], Li_3GaP_2 [79.943(1)–110.253(1)°], Li_2SiP_2 [102.669(9)–114.937(9)°], and Li_2GeP_2 [101.726(7)–112.609(7)°].

Comparison of Li_3InP_2 with the lighter homologues Li_3AlP_2 and Li_3GaP_2

Recently, we described the two isotopic phases Li_3AlP_2 and Li_3GaP_2 ,¹⁶ which crystallize in a distorted orthorhombic packing of phosphorus atoms in the space group $Cmce$ (no. 64) with lattice parameters $a = 11.5138(2)$, $b = 11.7634(2)$, $c = 5.8202(1)$ Å and $a = 11.5839(2)$, $b = 11.7809(2)$, $c = 5.8129(2)$ Å, respectively, both determined by Rietveld refinement at room temperature. The crystal structures are built up by corner- and edge-sharing TrP_4 (Tr = Al, Ga) tetrahedra in two-dimensional $^2_\infty[TrP_2^{3-}]$ layers. Based on a close packing of P atoms, the lithium atoms are located in all tetrahedral voids (Fig. 3). By contrast, Li_3InP_2 crystallizes in a tetragonal distorted phosphorus lattice in the space group $I4_1/acd$ (no. 142) with lattice parameters of $a = 12.03049(8)$ and $c = 23.9641(3)$ Å, determined by Rietveld refinement at room temperature, and as mentioned above, the single crystal structure determination reveals a three-dimensional structure with exclusively corner-sharing InP_4 tetrahedra for $t-Li_3InP_2$ (Fig. 1).

In order to gain additional insight into the experimentally observed structure types, we performed DFT-based structural optimizations for the Al, Ga and In compounds using the

PBESol functional²⁴ as implemented in CASTEP²⁵ (computational details are given in the ESI†). In addition to the experimentally determined unit cells we performed a substitutional “cross-check”: both modifications, orthorhombic $o-Li_3TrP_2$ and tetragonal $t-Li_3TrP_2$, were used for Tr = Al, Ga and In, starting either from the experimentally determined structure or from a hypothetical one obtained by substituting the Tr species. The DFT-optimized cell parameters are in excellent agreement with the experiment for the title compound (we obtained $a_{DFT} = 11.96$ Å and $c_{DFT} = 23.74$ Å); full results are listed in Table S7.† Fig. 4a shows the resulting energies, relative to the respective binary phosphides similar in spirit to our recent work on Li_9AlP_4 .¹⁵ We compute the DFT electronic energy, E , for the relaxed ternary structure as well as for Li_3P and the respective zinc blende-type phase of AlP, GaP or InP; the difference (in the sense of a “reaction energy”) then allows us to estimate the stability of the ternary phase:

$$\Delta E = E(Li_3TrP_2) - [E(Li_3P) + E(TrP)]$$

Negative values of ΔE therefore indicate that the ternary phase is stable with respect to the binaries (Fig. 4a).

The compounds Li_3TrP_2 are energetically favored over their respective binary components Li_3P and AlP, GaP and InP. The latter all adopt the cubic zinc blende type. The energy gain is significant considering the known stability of the zinc blende type that is most frequent among III–V semiconductors. More importantly, the *difference* in pairs of ΔE values allows us to compare the tendency for assuming either the $Cmce$ or the $I4_1/acd$ structure for all of the Li_3TrP_2 phases. For the Al and Ga compounds, the $Cmce$ structure is favored by about 0.06 and 0.03 eV per formula unit (f.u.), respectively; by contrast, the $I4_1/acd$ structure is preferred for Li_3InP_2 (by about 0.06 eV f.u.^{−1}), all in agreement with experiments. The stabilization of the title compound compared to the constituent binary phosphides is computed to be 0.31 eV f.u.^{−1} (indicated by a negative sign in the convention of Fig. 4a), which represents a significant gain in stability and explains the synthetic accessibility of the ternary compound. Whilst there will always remain a certain error due

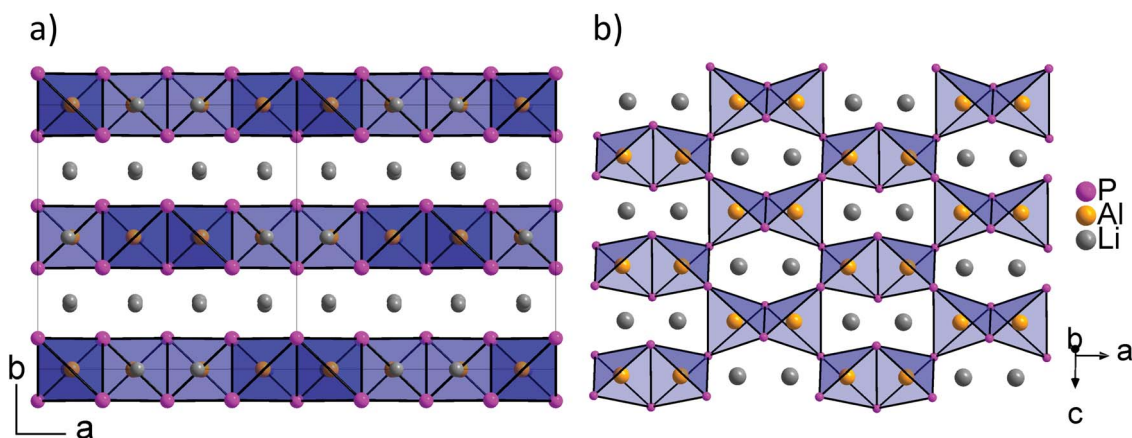


Fig. 3 Structural details of Li_3AlP_2 : (a) layers of $^2_\infty[AlP_2^{3-}]$ poly-anions are separated by lithium ions. (b) Top view of one $^2_\infty[AlP_2^{3-}]$ layer of dimers of two edge-sharing AlP_4 tetrahedra that are interconnected by vertex-sharing. Unfilled voids within the layer are filled with additional Li ions. AlP_4 tetrahedra are shown as blue polyhedra. Al, P and Li atoms are drawn in orange, purple and grey, respectively.



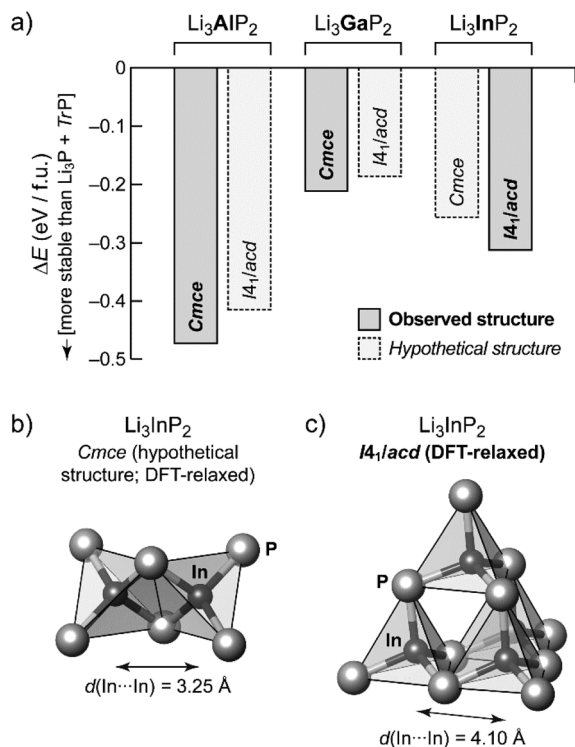


Fig. 4 First-principles DFT computations for Li_3AlP_2 , Li_3GaP_2 and Li_3InP_2 . (a) Computed total energies for DFT-relaxed structural models of the Li_3TrP_2 (Tr = Al, Ga, or In). Results are given relative to the respective binary phases; negative values indicate that the formation of the ternary compound is favorable. Results for experimentally observed structures correspond to solid lines and darker shading. Hypothetical structures, generated by cation substitution and DFT relaxation, are shown by dashed lines and lighter shading, and in all three cases these are less favorable than their respective counterpart, in agreement with experimental observations. (b) Structural fragment from a hypothetical, DFT-generated, $Cmce$ Li_3InP_2 structure, emphasizing the edge-sharing $[\text{InP}_4]$ tetrahedra, which may be compared to (c) the DFT-optimized $I4_1/acd$ Li_3InP_2 structure, from which a supertetrahedral fragment is shown.

to the DFT approximation and the neglect of thermal effects, we do trust that the computed trends shown in Fig. 4a are robust, and we note that they are fully consistent with the experimental observations.

As expected, the unit cell volume for the heavier homologues increases, however the In compound shows a much stronger increase: 788.30 \AA^3 for Al and 793.28 \AA^3 for Ga if compared to 867.10 \AA^3 ($=3468.39 \text{ \AA}^3:4$) for In. This correlates with a larger increase of the size of the InP_4 tetrahedron (8.8857 \AA^3) compared to AlP_4 (7.0897 \AA^3) and GaP_4 (7.1334 \AA^3).

The trends of the interatomic Tr–Tr (Tr = Al, Ga, In) distances in Li_3AlP_2 , Li_3GaP_2 and Li_3InP_2 are listed in Table 1. Regarding the different orthorhombic (Li_3AlP_2 , Li_3GaP_2) and tetragonal structures (Li_3InP_2), the interatomic distances of the metal atoms are shorter in the orthorhombic structures, where edge-sharing tetrahedra occur compared to the tetragonal structure, where only corner-sharing tetrahedra are present. One may ask for the origin of the preference of one structure type over the other when comparing all three phosphidotrirelates side-by-side. Interestingly, the results of the calculations are in agreement with Pauling's third rule. At least qualitatively and within the limits of such empirical concepts,²⁶ edge-sharing tetrahedra are disfavored on account of the repulsion of positively charged central atoms (Fig. 4b and c). This effect might be expected to be strongest in the In compound, where not only the ionic radius is the largest of the three, but the computed Mulliken charges for the series of $Cmce$ structures (Al: $+0.42e$, Ga: $+0.57e$, hypothetical In structure: $+0.65e$) appear to be consistent with an increasing repulsion of Tr atoms in the case of edge-sharing tetrahedra. Note that the Mulliken charges, derived from quantum-mechanical computation, are not to the same as the formal negative charge of the Tr atom using the Lewis valence model (Fig. 1b). Accordingly, a structure containing edge-sharing tetrahedra is observed for Li_3AlP_2 and Li_3GaP_2 , but not for Li_3InP_2 (Fig. 4c). This trend of the differences of the different metal to metal distances by DFT calculation is confirmed by the experimental interatomic Tr–Tr (Tr = Al, Ga, In) distances (Table 1). The experimental In–In distance is significantly longer than the Al–Al or Ga–Ga distances ($4.116(3) \text{ \AA}$ (In) vs. $3.028(5) \text{ \AA}$ (Al) and $3.089(2) \text{ \AA}$ (Ga)).

Comparison of Li_3InP_2 with the phosphidotetrelates Li_2SiP_2 and Li_2GeP_2

The crystal structure of Li_3InP_2 is related to the structure of Li_2SiP_2 and Li_2GeP_2 .^{8,13} The two latter isotypic phases also crystallize in the space group $I4_1/acd$ (no. 142), with lattice parameters of $a = 12.1111(1)$ and $c = 18.6299(4) \text{ \AA}$ for Li_2SiP_2 and $a = 12.3070(1)$ and $c = 19.0307(4) \text{ \AA}$ for Li_2GeP_2 and a slightly longer a , but much shorter c parameter as compared to Li_3InP_2 . A full comparison of the lattice parameters and the tetrahedral volumes in Li_3InP_2 , Li_2SiP_2 and Li_2GeP_2 is given in Table 2.

Assuming an average volume of 18 \AA^3 per heavy atom, the increase in cell volume corresponds approximately to the volume of 32 additional lithium atoms in the unit cell of Li_2SiP_2 . Besides the change in the number of Li atoms, also the larger volume of the InP_4 tetrahedra compared to $\text{SiP}_4/\text{GeP}_4$ (see Table 2) contributes to an overall increase of the volume. However,

Table 1 Comparison of the shortest interatomic Tr–Tr (Tr = Al, Ga, In) distances, the cell volume and the volume per formula unit in Li_3AlP_2 , Li_3GaP_2 and Li_3InP_2 from Rietveld refinements at room temperature¹⁶

	o- Li_3AlP_2	o- Li_3GaP_2	t- Li_3InP_2
Cell volume/ \AA^3	788.29(2)	793.28(2)	3468.39(6) ($3468.39:4 = 867.10$)
Volume per formula unit/ \AA^3	98.54	99.16	108.38
Tetrahedron volume/ \AA^3	7.0897	7.1334	8.8857
Tr–Tr distances/ \AA	3.028(5)	3.089(2)	4.116(3)



Table 2 Comparison of the tetrahedral volumes of InP_4 , SiP_4 and GeP_4 , the distances and angles between the supertetrahedra and the lithium coordination in Li_3InP_2 , Li_2SiP_2 and Li_2GeP_2 obtained from single crystal structure determination. The values for Li_2SiP_2 and Li_2GeP_2 are taken from the literature^{8,13}

	Li_3InP_2	Li_2SiP_2	Li_2GeP_2
$a/\text{\AA}$	12.0007(2)	12.1111(1)	12.3070(1)
$c/\text{\AA}$	23.917(5)	18.6299(4)	19.0307(4)
$V/\text{\AA}^3$	3447.7(1)	2732.61(7)	2882.42(9)
$V_{(\text{T}1/\text{T}2)\text{P}_4 \text{ tetrahedra}}/\text{\AA}^3$	8.7944	5.8042	6.4083
Distances (Å) between the centers of the T2-supertetrahedra	8.4729(1), 8.4899(9)	7.6395(1), 8.5638(1)	7.7782(1), 8.7023(1)

this increase is highly anisotropic, since in Li_3InP_2 the lattice parameter c increases strongly, whereas the lattice parameter a is even slightly shorter compared to the one in Li_2SiP_2 and Li_2GeP_2 .

Fig. 5 shows a comparison of the structures of Li_3InP_2 and Li_2SiP_2 viewed along the a and c direction. In Li_3InP_2 the InP_4 tetrahedra respectively the T2-supertetrahedra are aligned in an almost parallel fashion, whereas in Li_2SiP_2 the T2-supertetrahedra are rotated along the tetragonal axes. Interestingly, the parallel alignment in Li_3InP_2 leads to a slight decrease of the a and b axes despite the higher lithium content, but to a significant increase of the c axes.

In Table 3 the Wyckoff positions in Li_3InP_2 and Li_2SiP_2 are compared (Li_2GeP_2 is omitted since it is isotypic to Li_2SiP_2). The higher Li content of the In compound arises from the occupation of two 32g Wyckoff sites instead of two 16f sites in the tetrelates. As a consequence, the coordination environments of the lithium atoms in the structures are different. The coordination of the lithium atoms in Li_3InP_2 and Li_2SiP_2 by phosphorus is illustrated in Fig. S2 and S8,[†] respectively. The positions Li1 and Li3 are similarly coordinated by four phosphorus atoms forming a distorted tetrahedron. By contrast, Li2 fills a strongly distorted octahedral void of phosphorus atoms with significant longer Li–P distances compared to Li1 and Li3.

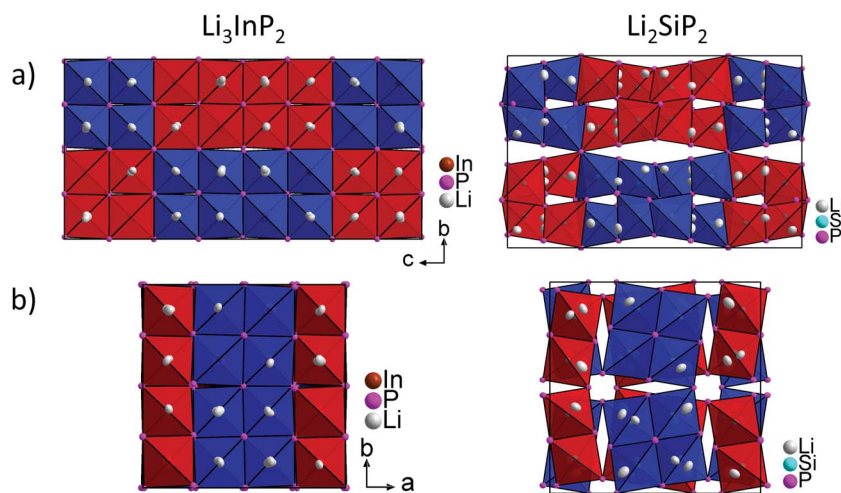


Fig. 5 Comparison of the crystal structures of Li_3InP_2 (left) and Li_2SiP_2 (right). (a) The unit cell in a direction. (b) The unit cell in c direction. The InP_4 and SiP_4 tetrahedra are shown in blue and red. Both structures exhibit two independent diamond-like networks of T2-supertetrahedra. The different networks are drawn in blue and red, respectively.

Table 3 Comparison of Wyckoff positions and atomic coordinates in Li_3InP_2 and Li_2SiP_2

Atom	Li_3InP_2				Li_2SiP_2			
	Wyck.	x	y	z	Wyck.	x	y	z
In1/Si	32g	0.11730(2)	0.12523(2)	0.31365(2)	32g	0.08345(2)	0.12967(2)	0.30710(1)
P1	16d	0	1/4	0.00065(2)	16d	0	1/4	0.23093(2)
P2	16e	0.23884(3)	0	1/4	16e	0.18335(3)	0	1/4
P3	32g	0.25031(2)	0.25604(2)	0.12516(2)	32g	0.21330(2)	0.21711(2)	0.37222(2)
Li1	32g	0.1279(2)	0.3720(2)	0.0615(1)	16f	0.0946(2)	0.3446(2)	1/8
Li2	32g	0.1179(2)	0.1250(2)	0.0651(1)	16f	0.1506(2)	0.0995(2)	1/8
Li3	32g	0.3635(2)	0.1212(2)	0.19053(9)	32g	0.3426(2)	0.1271(2)	0.2173(1)



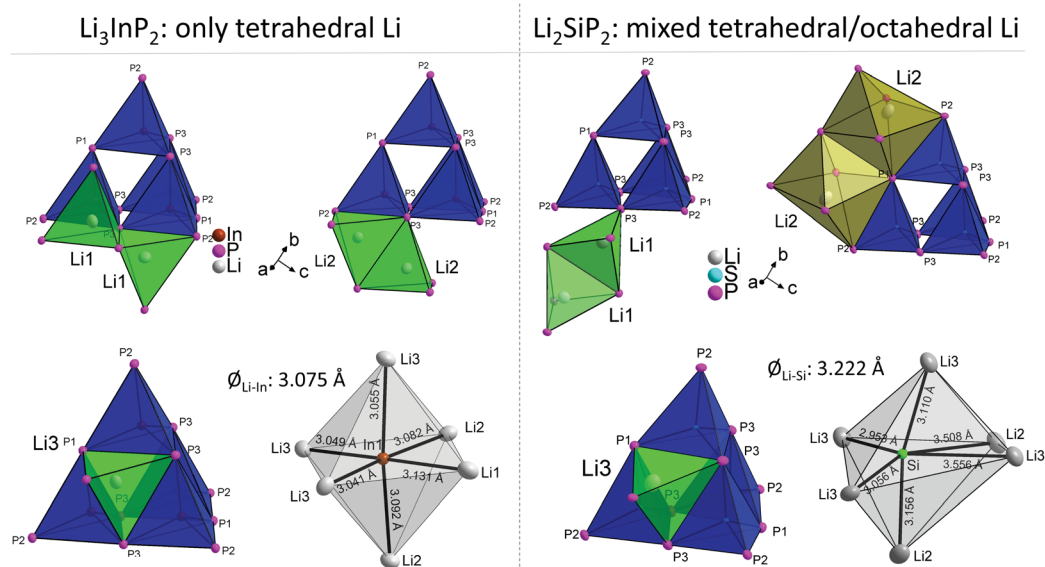


Fig. 6 Comparison of the different lithium atoms and how they are connected to the T2-supertetrahedra in Li_3InP_2 (left) and Li_2SiP_2 (right). For clarity, just one or two polyhedra are shown for the lithium atoms, respectively. In Li_3InP_2 , all lithium atoms (Li1, Li2 and Li3) are in tetrahedral voids. The tetrahedra of Li1 and Li2 are connected *via* one edge or one corner to the supertetrahedron. The tetrahedron of Li3 is connected *via* one face to the center of the supertetrahedron's face. In Li_2SiP_2 , Li1 and Li3 are placed in tetrahedral voids (green) whereas Li2 resides in an octahedral void (orange). As in Li_3InP_2 , the tetrahedron of Li3 is connected *via* one face to the center of the supertetrahedron's face. By contrast, the strongly distorted tetrahedron of Li1 is only connected *via* one corner to the supertetrahedron. The strongly distorted octahedra of Li2 are connected *via* edges to the supertetrahedron. In Li_3InP_2 , the indium atoms are octahedrally coordinated by lithium atoms with an average Li–In distance of 3.075 Å. In Li_2SiP_2 , the silicon atoms are coordinated by a strongly distorted octahedron of lithium atoms with an average Li–Si distance of 3.222 Å.

Here, the lithium atom Li2 is not located in the center of gravity of the octahedron but shows two much longer distances to neighboring P atoms of the distorted octahedron, resulting in a butterfly-type coordination of four P atoms. Interestingly, despite the smaller amount of Li atoms in Li_2SiP_2 , not all the tetrahedral voids are occupied. In both compounds 25% of the tetrahedral voids are occupied by In or Si. Whereas all of the remaining 75% tetrahedral voids in Li_3InP_2 are filled with Li, only 37.5% are occupied by Li in Li_2SiP_2 . In the latter, however, Li atoms occupy 25% of the distorted octahedral voids.

The different occupation of voids in Li_3InP_2 and Li_2SiP_2 also results in a different coordination of the supertetrahedra by lithium, which is shown in Fig. 6.

The different Li coordination arises from the different charges of the supertetrahedra $\text{Si}_4\text{P}_8^{8-}/\text{Ge}_4\text{P}_8^{8-}$ and $\text{In}_4\text{P}_8^{12-}$ (Fig. 1b). In Li_3InP_2 the lithium atoms form an almost regular octahedron around the indium atom with In–Li distances in the narrow range of 3.041 to 3.131 Å with an average of 3.075 Å, whereas in Li_2SiP_2 the octahedron formed by lithium atoms around silicon is strongly distorted with longer average distances of 3.222 Å and values between 2.958 and 3.556 Å. As a consequence, also octahedral voids of P atoms are filled with Li ions in Li_2SiP_2 .

Impedance spectroscopy

For Li_3InP_2 two impedance measurements were performed to determine the ionic conductivity. The results are shown in Fig. S10.† The semi-circle can be described as parallel circuit element of a resistor and a constant phase element (R/Q). For

the constant phase element the fit of the data acquired at 298 K resulted in α values of ≈ 0.99 and Q parameters of $\approx 2 \times 10^{-8} \text{ F s}^{(\alpha-1)}$; the conductivity was determined to $\sigma(\text{Li}_3\text{InP}_2) = 2.8(2) \times 10^{-9} \text{ S cm}^{-1}$ at 298 K (obtained from two independently measured cells). DC polarization measurements in the range from 50 to 150 mV reveal an electronic conductivity of $2.7(3) \times 10^{-9} \text{ S cm}^{-1}$ at 298 K (based on the standard deviation of two cells). The conductivity value obtained by DC polarization measurements is in the same range as the value obtained by PEIS measurements. Hence, the Nyquist plot shows only the semi-circle of the electronic conductivity, and no semi-circle for the ionic conductivity appears.

Conclusions

Li_3InP_2 is the first lithium phosphidoindate and can be described as a tetragonally distorted fcc lattice of P atoms (space group $I4_1/acd$), in which the In atoms occupy tetrahedral voids, thus forming a polyanionic framework of InP_4 supertetrahedra. The lithium atoms occupy the remaining tetrahedral voids. The structure of the compound is not isotopic to the previously reported ones of the lighter homologues, the orthorhombic compounds Li_3AlP_2 and Li_3GaP_2 (space group $Cmce$), which feature 2D layers of connected tetrahedra. First-principles DFT computations confirm the trend for the Al and Ga (In) compounds to crystallize in the orthorhombic (tetragonal) structure, respectively, which might originate in the different repulsive cation–cation interactions in both structures. Impedance spectroscopy reveals a very low electronic, but no



ionic conductivity, whereas Li_2SiP_2 and Li_2GeP_2 show a moderate ionic mobility ($2.2(3) \times 10^{-7} \text{ S cm}^{-1}$ at 293 K and $1.5(3) \times 10^{-7} \text{ S cm}^{-1}$ at 300 K, respectively).^{8,13} The geometrical analysis of the Li positions shows that in Li_3InP_2 all tetrahedral voids are fully occupied by lithium, whereas in Li_2SiP_2 and Li_2GeP_2 tetrahedral voids remain empty, and especially strongly distorted octahedral voids are filled. In accordance with the observations in fcc phosphide-based lithium ion conductors such as Li_9AlP_4 ,¹⁵ lithium diffusion preferably appears on pathways *via* partially occupied octahedral sites.

Overall, these results demonstrate that even though crystal structures of phosphide compounds can contain complex polyanionic networks, a relatively simple description in terms of distorted close-packed arrangements of phosphorus atoms gives better insight for the description of lithium ion mobility. The title compound Li_3InP_2 provides a missing link in two respects: (i) it shows the structure changes in the series Li_3TrP_2 for Tr = Al, Ga, In, and (ii) it shows changes in lithium ion mobility in the series Li_3InP_2 , Li_2SiP_2 and Li_2GeP_2 .

Author contributions

TMFR carried out the crystal structure determination by single crystal and powder X-ray diffraction, performed the impedance spectroscopy measurements and wrote the manuscript draft. VLD carried out the DFT computations and provided discussion. JM contributed to the synthesis and data evaluation. GRS performed NMR experiments. TF designed research, provided guidance, and critically reviewed the manuscript.

Conflicts of interest

The authors declare no competing financial interest.

Acknowledgements

The work was carried out as part of the research project ASSB coordinated by ZAE Bayern. The project is funded by the Bavarian Ministry of Economic Affairs, Regional Development and Energy. V. L. D. acknowledges a Leverhulme Early Career Fellowship. The authors would like to acknowledge the use of the University of Oxford Advanced Research Computing (ARC) facility in carrying out this work (see DOI: 10.5281/zenodo.22558).

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